## NSN 5961-01-095-8469

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View Online at https://aerobasegroup.com/nsn/5961-01-095-8469 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 15.00 amperes source cutoff current and 50.00 amperes source cutoff current **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:** 81349-mil-s-19500/464 government specification Shelf Life: N/a **Unit Of Measure:** 

Fiig:

No

Demilitarization: